

Part A. (80 %)

1. (10 %) (Ray Optics) Numerical Aperture of an Optical Fiber

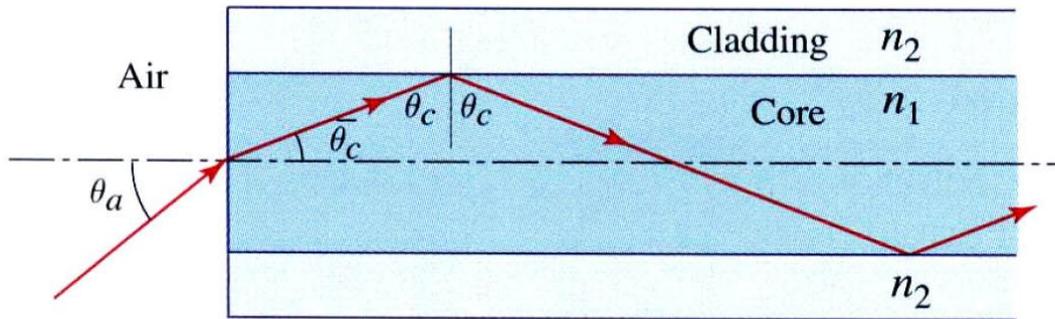
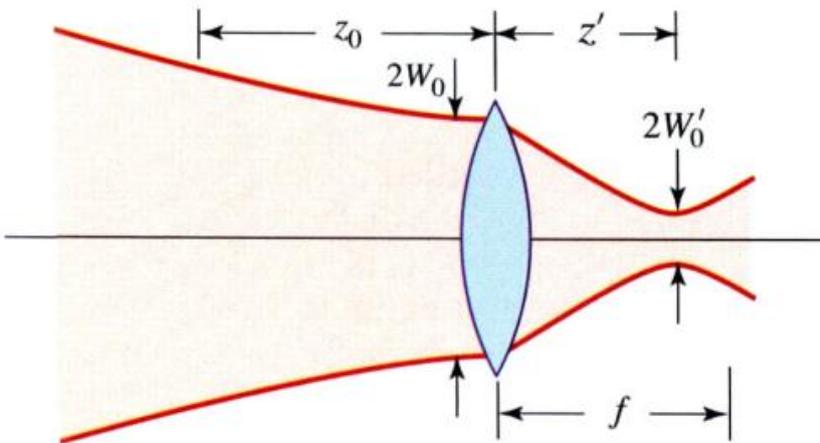


Figure 1.2-18 Acceptance angle of an optical fiber.

Please derive $NA = \sin\theta_a = \sqrt{n_1^2 - n_2^2}$

2. (10 %) (Wave Optics) Please derive Snell's law. (Hint: using "the wavefronts of the two waves match", or the Fermat's Principle.)
 3. (10 %) (Beam Focusing) For a lens placed at the waist of a Gaussian beam, as shown below. Please derive the waist W_0' and distance z_0' of the transmitted beam.



4. (10 %) (Reflection and Refraction)

$$r_x = \frac{n_1 \cos \theta_1 - n_2 \cos \theta_2}{n_1 \cos \theta_1 + n_2 \cos \theta_2}, \quad t_x = 1 + r_x,$$

$$r_y = \frac{n_1 \sec \theta_1 - n_2 \sec \theta_2}{n_1 \sec \theta_1 + n_2 \sec \theta_2}, \quad t_y = (1 + r_y) \frac{\cos \theta_1}{\cos \theta_2}.$$

(6.2-8)
TE Polarization
(6.2-9)
TM Polarization
Fresnel Equations

Please derive Brewster Angle, and calculate it at the n_1/n_2 interface when $n_1=1$, and $n_2=1.5$.

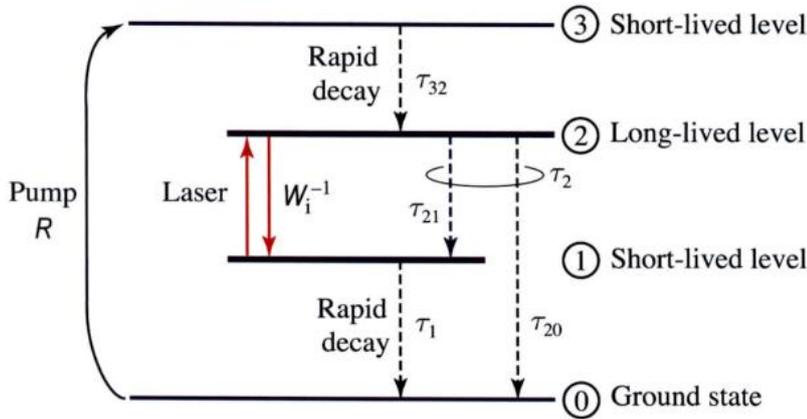
5. (10 %) (Resonator Optics)

Please derive the Density of Modes of 3D resonator ($M(\nu) = \frac{8\pi\nu^2}{c^3}$)

6. (10 %) (Photon and Atom)

Please plot the radiation processes of the spontaneous emission, stimulated emission, and absorption.

7. (10 %) (Lasers)



Please write down the rate equations of level 1 and level 2.

8. (10 %) (Lasers)

Please explain the difference of “Q-switched laser” and “Mode-locked Laser”.

Part B. (70 %)

9. (10%) (Fermi level)

Given the thermal equilibrium carrier concentrations in the conduction and valance bands as

$$n = N_c \exp\left(-\frac{E_c - E_f}{kT}\right) \quad p = N_v \exp\left(-\frac{E_f - E_v}{kT}\right) \quad \text{where} \quad N_{c,v} = 2\left(2\pi m_{c,v} kT / h^3\right)^{3/2}$$

(a) Find the expression for the **Fermi level** E_f of an *intrinsic* semiconductor

(b) Find the expression for the **Fermi level** of a doped semiconductor as a function of the *doping level* (E_D donor level) and E_f from (a) when $m_c = m_v$

10. (10%) (Laser diodes)

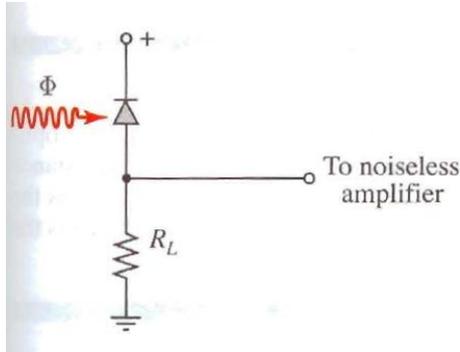
Among the **threshold current** for InGaAsP homostructure laser diode I_{homo} , Heterostructure laser diode I_{hetero} , and Multi-Quantum-Well laser diode I_{MQW} , which one is the *largest* and which one is the *smallest*? Please explain **why**?

11. (10%)(Photodiode Detector)

For a particular p-i-n photodiode, a pulse of light containing 6×10^{12} incident photons at wavelength $\lambda_0 = 1550$ nm gives rise to, on average, 2×10^{12} electrons collected at the terminals of the device. Determine the **quantum efficiency** η and the **responsivity** \mathcal{R} of the photodiode at this wavelength.

12. (10%) (Photo detector SNR of resistance limited optical receiver)

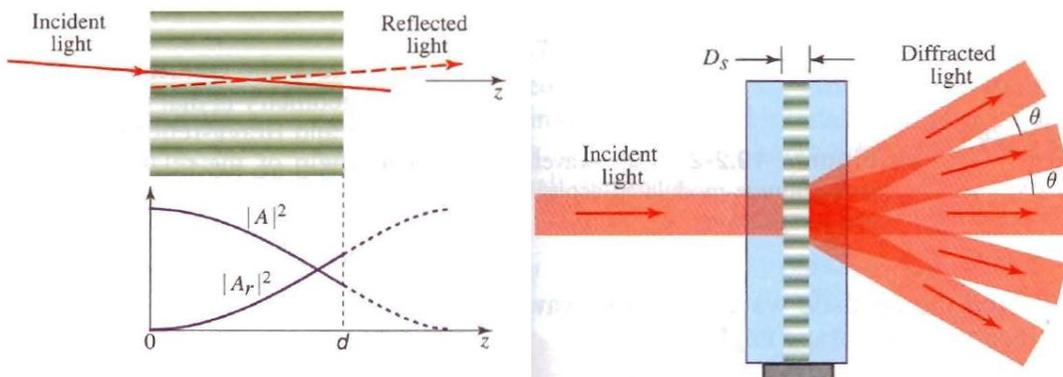
Assume that the optical receiver shown in the Fig. makes use of an ideal p-i-n photodiode ($\eta = 1$) and the resistance $R_L = 50$ at $T = 300^0$ K. The bandwidth is $B = 100$ MHz. At what value of **photon flux** Φ is the photoelectron-noise current variance equal to the resistor thermal-noise current variance? What is the corresponding **optical power** at $\lambda_0 = 1550$ nm?



$$\sigma_q = \frac{\sigma_r}{2Be}, \quad \sigma_q \approx \frac{\sqrt{B}}{100}, \quad SNR = \frac{(e\bar{G}\eta\Phi)^2}{2e^2\bar{G}^2\eta B\Phi F + \sigma_r^2}, \quad G=1, F=1$$

13(10%) Acoustic-Optics

Describe the *difference* in the diffraction of an optical plane wave by a **thick** acoustic beam (plane wave acoustic beam) and a **thin** acoustic beam.



14(10%) Electro-Optics

- Explain what is **Pockels** effect and what is **Kerr** effect.
- Explain the **intensity modulation** in a Mach-Zehnder interferometer with an electro-optic phase modulator

15(10%) Nonlinear Optics

- Explain the **phase matching condition** in **Second Harmonic Generation**.
- Explain **Optical Phase Conjugation** using **Four Waves Mixing**.